U nusual charge transport and spin response of doped bilayer triangular antiferrom agnets

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W ithin the t-J m odel, the charge transport and spin response of the doped bilayer triangular antiferrom agnet are studied by considering the bilayer interaction. A lthough the bilayer interaction leads to the band splitting in the electronic structure, the qualitative behaviors of the physical properties are the same as in the single layer case. The conductivity spectrum shows the low energy peak and unusual m idinfrared band, the tem perature dependent resistivity is characterized by the nonlinearity m etallic-like behavior in the higher tem perature range, and the deviation from the m etallic-like behavior in the lower tem perature range, and the commensurate neutron scattering peak near the half-lling is split into six incommensurate peaks in the underdoped regime, with the incommensurability increases with the hole concentration at lower dopings, and saturates at higher dopings.

74.20 M n, 74.25 Fy, 75.25.+ z

I. IN TRODUCTION

It has become clear in the past ten years that the most rem arkable expression of the nonconventional physics of doped cuprates is found in the norm al-state^{1;2}. These unusual norm al-state properties are due to the special m icroscopic conditions: (1) Cu ions situated in a squareplanar arrangem ent and bridged by oxygen ions (CuO₂ plane), (2) weak coupling between neighboring layers, and (3) doping in such a way that the Ferm i level lies near the middle of the Cu-O bond, where one com m on feature is the square-planar Cu arrangem ent^{1;2}. In the underdoped and optim ally doped regim es, it has been shown from the transport experiments^{1;3} that the ratio of the c-axis and in-plane resistivity $R = _{c} (T) = _{ab} (T)$ 100 to $R > 10^5$, this rejects that the ranges from R charged carriers are tightly con ned to the CuO₂ planes. This large magnitude of the resistivity anisotropy also leads to the general notion that the physics of these m aterials is alm ost entirely two-dimensional (2D), and can be well described by a single CuO_2 plane⁴. How ever, this physical picture seems to be incompatible with the fact that the superconducting transition tem perature T_c is closely related to the number of CuO₂ planes per unit cell, with single layer materials of a fam ily generically having lower T_c than bilayer or trilayer m aterials^{1;2}. Furtherm ore, som e essential di erences of the magnetic behaviors between doped single layer and bilayer cuprates have been found^{5;6}. In the underdoped regime, it has been shown from the experiments that only incommensurate neutron scattering peaks for the single layer lanthanum cuprate are observed⁵, how ever, both low-energy incommensurate neutron scattering peaks and high-energy commensurate [,] resonance for the bilayer yttrium cuprate in the normal state are detected⁶. These experimental results highlight the importance of some sort of coupling between the CuO₂ planes within a unit cell. On the other hand, the bilayer band splitting in the doped bilayer cuprates was shown by the band calculation⁷, and clearly observed⁸ recently by the angle-resolved-photoem ission spectroscopy in the underdoped and overdoped bilayer cuprates. This bilayer band splitting is due to a nonvanishing intracell coupling. Moreover, the magnitude of the bilayer splitting is constant over a large range of dopings⁹.

However, many materials with the Cu arrangements on 2D non-square lattices have been synthetized^{10{12}. In particular, it has been found from the experiments that there is a class of doped cuprates, RCuO₂₊, R being a rare-earth element, where the Cu ions are not arranged on a square-planar, but on a triangular-planar lattice¹⁰, therefore allowing a test of the geometry effect on the norm al-state properties, while retaining som e other unique special m icroscopic features of the Cu-O bond. Since the strong electron correlation is common for both doped square and triangular antiferrom agnets, it is expected that the unconventional norm al-state properties existing in the doped square antiferrom agnet m ay also be seen in the doped triangular antiferrom agnet. However, within the t-J model, $w e^{13;14}$ have discussed the charge transport and spin response of the doped single layer triangular antiferrom agnet in the underdoped regime, and found that the normal-state properties of the doped single layer triangular lattice antiferrom agnet are much di erent from these of the doped single layer square lattice antiferrom agnet since the strong geom etry e ect in the triangular lattice system. The conductivity spectrum shows the unusual behavior at low energies and

anom alous midinfrared band separated by the chargetranfer gap, in contrast with the doped square lattice antiferrom agnet, the resistivity exhibits a nonlinearity in tem peratures, and the com m ensurate neutron scattering peak near the half-lling is split into six incom m ensurate scattering peaks away from the half-lling. Considering these highly unusual charge transport and spin response in the underdoped regime, a natural question is what is the e ect of the intracell coupling on the charge transport and spin response of the doped bilayer triangular antiferrom agnet. On the other hand, the undoped bilayer triangular antiferrom agnet is a good candidate for a 2D quantum system with the resonating valence bond spin liquid due to the strong geometry spin frustration and quantum interference e ect between the layers¹⁵. This spin liquid state would be particularly attractive, given the intensive work on the spin liquid states on the square lattice, especially in connection with the superconductivity of doped cuprates⁴. M oreover, it has been shown that the doped and undoped triangular antiferrom agnets present a pairing instability in an unconventional channel¹⁶. In this paper, we apply the ferm ion-spin theory¹⁷ to study the charge transport and spin response of the doped bilayer triangular antiferrom agnet. We hope that the information from the present work may induce further experim entalworks in doped antiferrom agnets on the non-square lattice.

The paper is organized as follows. The theoretical fram ework is presented in Sec. II, where the singleparticle holon and spinon G reen's functions are calculated based on the t-J m odel by considering the bilayer interaction. W ithin this theoretical fram ework, we discuss the charge transport of the doped bilayer triangular antiferrom agnet in Sec. III. It is shown that the conductivity spectrum shows a low-energy peak and unusual m idinfrared band, while the tem perature dependent resistivity is characterized by the nonlinearity m etallic-like behavior in the higher tem perature range, and the deviation from the metallic-like behavior in the lower tem perature range. In Sec. IV, the spin response of the doped bilayer triangular antiferrom agnet is studied. Our result shows that the commensurate neutron scattering peak near the half-lling is split into six incom m ensurate peaks in the underdoped regime, where the incommensurability is doping dependent, and increases with the hole concentration at lower dopings, and saturates at higher dopings. Sec. V is devoted to a sum mary and discussions. Our results also show that although the bilayer interaction leads to the band splitting in the electronic structure, the qualitative behavior of the charge transport and spin response are the sam e as in the single layer $case^{13;14}$.

II. THEORET ICAL FRAM EW ORK

As in the doped single layer triangular antiferrom agnet^{4;16}, the essential physics of the doped bilayer triangular antiferrom agnet is well described by the bilayer t-J m odel on the triangular lattice, and can be expressed as,

$$H = t_{k} C_{ai}^{y} C_{ai+} + t_{?} (C_{1i}^{y} C_{2i} + hx)$$

$$X C_{ai}^{ai} C_{ai+} + J_{k} S_{ai} S_{i+} + J_{?} S_{1i} S_{1i}; (1)$$

where the sum mation within the plane is over all sites i, and for each i, over its nearest-neighbor ^, a = 1, 2 is plane indices, C_{ai}^{y} (C_{ai}) is the electron creation (annihilation) operator, $S_{ai} = C_{ai}^{y} \sim C_{ai}=2$ are spin operators with ~ = ($_{x}; _{y}; _{z}$) as Pauli matrices, and is the chemical potential. The bilayer t-J model (1) is supplemented by the single occupancy local constraint

 $C_{ai}^{\gamma} C_{ai}$ 1. This local constraint re ects the strong electron correlation in the doped antiferrom agnet, and can be treated properly in analytical form within the ferm ion-spin theory¹⁷ based on the charge-spin separation,

$$C_{ai''} = h_{ai}^{Y} S_{ai}; \quad C_{ai\#} = h_{ai}^{Y} S_{ai}^{+}; \quad (2)$$

with the spinless ferm ion operator h_{ai} keeps track of the charge (holon), while the pseudospin operator S_{ai} keeps track of the spin (spinon), and then the low-energy behavior of the bilayer t-J m odel (1) can be rewritten in the ferm ion-spin representation as,

37

where S_{ai}^{+} (S_{ai}) is the pseudospin raising (bw ering) operator, $J_{ke} = J_k [(1 \ x)^2 \ _k^2]$, $J_{?e} = J_? [(1 \ x)^2 \ _2^2]$, x is the hole doping concentration, and $_k = hh_{ai}^y h_{ai} + i$ and $_{?} = hh_{1i}^y h_{2i}$ i are the holon particle-hole order param eters. The spinon and holon m ay be separated at the m ean-eld (MF) level, but they are strongly coupled beyond the MF approxim ation due to the strong holon-spin interaction.

In the bilayer system, because there are two coupled planes, then the energy spectrum has two branches. In

this case, the one-particle holon and spinon G reen's functions are m atrices, and are expressed as,

D (i j; ⁰) = D_L (i j; ⁰)
+
$$_{x}D_{T}$$
 (i j; ⁰); (4a)

g(i j; ⁰) = g_L(i j; ⁰)
+
$$_{x}g_{T}$$
(i j; ⁰); (4b)

respectively, where the longitudinal and transverse parts are de ned as,

$$D_{L}(i j; ^{0}) = hT S_{ai}^{+}()S_{aj}(^{0})i;$$
 (5a)

$$g_{L}$$
 (i j; ⁰) = hT h_{ai} () h_{aj}^{y} (⁰)i; (5b)

$$D_{T}$$
 (i j; ⁰) = hT S_{ai}^{+} () $S_{a^{0}j}$ (⁰)i; (5c)

$$g_{T}$$
 (i j; ⁰) = hT h_{ai} () $h_{a^{\circ}i}^{V}$ (⁰) i; (5d)

with a \pm a⁰. At the half-lling, the bilayer t-J model (3) is reduced as the bilayer antiferrom agnetic H eisenberg model. It has been show n¹⁸ that as in the square lattice, there is indeed the antiferrom agnetic long-rangeorder (AFLRO) in the ground state of the single layer triangular antiferrom agnetic H eisenberg m odel, but this AFLRO is destroyed more rapidly with increasing dopings than on the square lattice due to the strong geom etry frustration. Since the quantum interference e ect between the layers in the bilayer triangular antiferrom agnet does not favor the magnetic order for spins, then AFLRO in the doped bilayer triangular antiferrom agnet is suppressed m ore fastly than the doped single layer antiferrom agnet, therefore away from the half-lling, there is no AFLRO for the doped bilayer triangular antiferromagnet, i.e., $hS_{ai}^{z}i = 0$. W ithin the ferm ion-spin formalism, the MF theory of the doped square antiferrom agnet in the underdoped and optim ally doped regimes without AFLRO has been developed¹⁹. Following thier discussions, the MF holon and spinon G reen's functions of the doped bilayer triangular antiferrom agnet are obtained as,

$$g_{L}^{(0)}(k;!) = \frac{1}{2} \frac{X}{\underset{l=1}{\overset{(1)}{=}} \frac{1}{k}} \frac{1}{\underset{k}{\overset{(1)}{=}}};$$
 (6a)

$$g_{T}^{(0)}(k;!) = \frac{1}{2} X_{(1)^{+1}} \frac{1}{! K_{k}^{(1)}}; \qquad (6b)$$

$$D_{L}^{(0)}(k;!) = \frac{1}{2} \frac{X}{=_{1;2}} \frac{B_{k}^{()}}{!^{2} (!_{k})^{2}}; \qquad (6c)$$

$$D_{T}^{(0)}(\mathbf{k};!) = \frac{1}{2} X_{1}(1)^{+1} \frac{B_{k}^{()}}{!^{2}(!_{k})^{2}}; \quad (6d)$$

respectively, where $B_k^{()} = [(2_k _k^z + _k)_k (_k _k + 2_k^z)] J_{?e} [_? + 2_?^2 (1)] [_? + (1)], = 2Z J_{ke}, k = 1 + 2t_k _k = J_{ke}, ? = 1 + 4t_? ? = J_{?e}, k = [cosk_x + 2 cos(k_x = 2)cos(3k_y = 2)] = 3, and Z is the num ber of the$

nearest neighbor sites within the plane, while the MF holon and spinon excitation spectra are given by,

$$\binom{()}{k} = 2Z t_{k \ k \ k} + 2 \ _{2} t_{2} \ (1)^{+1} + ;$$
(7a)
$$\binom{(!)}{k}^{()} = A_{1} \ _{k}^{2} + A_{2} \ _{k} + A_{3}$$

+
$$(1)^{+1} (X_{1 k} + X_{2});$$
 (7b)

w ith

$$A_{1} = {}_{k} {}^{2} \left(\frac{1}{2} {}_{k} + {}_{k} {}_{k}^{z}\right); \qquad (8a)$$

$$A_{2} = {}_{k} {}^{2} \left[\left(1 {}_{z}\right) {}_{z} {}_{z} {}_{z} {}_{k} {}_{k} + {}_{k}^{z}\right) \\ {}_{(C_{k}^{z} + \frac{1}{2}C_{k}) {}_{z} {}_{z$$

$$A_{3} = {}^{2} \left[(C_{k}^{z} + \frac{1}{2} {}_{k}^{2}C_{k}) + \frac{1}{4Z} (1) (1 + {}^{2}_{k}) \right]$$

$$+ \frac{1}{Z} \left(\frac{1}{2} {}_{k} + {}_{k} {}_{k}^{z} \right) \right]$$

$$+ J_{?e} \left[{}_{k} {}_{?}C_{?} + 2C_{?}^{z} \right] + \frac{1}{4} J_{?e}^{2} \left({}_{?}^{2} + 1 \right); \quad (8c)$$

$$K = J_{e} \left[{}_{k} {}_{?}C_{?} + 2C_{?}^{z} \right] + \frac{1}{4} J_{?e}^{2} \left({}_{?}^{z} + 1 \right); \quad (8c)$$

$$X_{1} = J_{2e} \left[\frac{1}{2} \left(\begin{array}{c} 2 \\ k \end{array} + \begin{array}{c} k \\ k \end{array} \right) + \begin{array}{c} k \\ k \end{array} \right] + \begin{array}{c} k \\ k \end{array} \right] \left(\begin{array}{c} 2 \\ k \end{array} \right) + \begin{array}{c} k \\ k \end{array} \right) + \begin{array}{c} k \\ k \end{array} \right] \left(\begin{array}{c} 2 \\ k \end{array} \right) + \begin{array}{c} k \\ k \end{array} \right) \left(\begin{array}{c} 2 \\ k \end{array} \right) + \begin{array}{c} k \\ k \\ k \end{array} \right) \left(\begin{array}{c} 2 \\ k \end{array} \right) \left(\begin{array}{c} 2 \\ k \end{array} \right) + \begin{array}{c} k \\ k \\ k \end{array} \right) \left(\begin{array}{c} 2 \\ k \\ k \end{array} \right) \left(\begin{array}{c} 2 \\ k \\ k \end{array} \right) + \begin{array}{c} k \\ k \\ k \end{array} \right) \left(\begin{array}{c} 2 \\ k \end{array} \right) \left(\begin{array}{c} 2$$

where the spinon correlation functions $_{k} = hS_{ai}^{+}S_{ai+}^{-}i$, $_{k}^{z} = hS_{ai}^{z}S_{ai+}^{z}$, i, $_{?} = hS_{1i}^{+}S_{2i}^{-}i$, $_{?}^{z} = hS_{1i}^{z}S_{2i}^{z}i$, $C_{k} = (1=Z^{2})^{P}$, $_{n}hS_{ai+}^{+}$, S_{pai+}^{-} , $_{n}i$, $C_{k}^{z} = (1=Z^{2})^{P}$, $_{n}hS_{ai+}^{z}hS_{ai+}^{-}hi$, $C_{k}^{z} = (1=Z^{2})^{P}$, $_{n}hS_{ai+}^{+}hS_{ai+}^{-}hi$, $C_{k}^{z} = (1=Z^{2})^{P}$, $_{n}hS_{ai+}^{+}hS_{ai+}^{-}hi$, $hS_{2i}^{+}S_{1i+}^{-}hi$, and $C_{?}^{z} = (1=Z)^{P}$, $hS_{1i}^{z}S_{2i+}^{z}hi$. In order to satisfy the sum rule for the correlation function $hS_{ai}^{+}S_{ai}^{-}i = 1=2$ in the absence of AFLRO, a decoupling parameter has been introduced in the MF calculation, which can be regarded as the vertex correction¹⁹. As a result of selfconsistent motion of holons and spinons, all these meaneld order parameters, decoupling parameter, and the chem ical potential are determ ined self-consistently.

In this paper we hope to discuss the optical, transport, and magnetic properties of the doped bilayer triangular antiferrom agnet, then the second-order corrections for holons and spinons due to the holon-spinon interaction are necessary for the proper description of the holon motion in the background of the magnetic uctuation and spinon motion in the background of the charged holon uctuation. Within the fermion-spin theory, the fullholon and spinon G reen's functions of the doped single layer triangular antiferrom agnet have been evaluated by considering the holon-spinon interaction^{13;14}. A coording to these discussions, we obtain the full holon and spinon G reen's functions of the doped bilayer triangular antiferrom agnet by the loop expansion to the secondorder as,

$$g^{1}(k;!) = g^{(0)1}(k;!)$$
 (9a)

$$D^{-1}(k;!) = D^{(0)-1}(k;!)$$
 (s) (k;!); (9b)

where ${}^{(h)}(k;!) = {}^{(h)}_{L}(k;!) + {}_{x} {}^{(h)}_{T}(k;!)$ is the second-order holon self-energy from the spinon pair bubble, with the longitudinal and transverse parts are obtained as,

respectively, and ${}^{(s)}(k;!) = {}^{(s)}_{L}(k;!) + {}_{x}{}^{(s)}_{T}(k;!)$ is the second-order spinon self-energy from the holon pair bubble, with the longitudinal and transverse parts are obtained as,

respectively, where

^(h) (k;p;q;!) =
$$\frac{B_{q+p}^{(0)}B_{q}^{(1)}}{32!_{q+p}^{(0)}!_{q}^{(1)}} Z t_{k} [q+p+k+qk] + t_{q,k}] + t_{p} [(1)^{+\infty} + (1)^{0+\infty}]^{2} + \frac{F_{0,\infty}^{(2)} (k;p;q)}{1 + !_{q+p}^{(0)} + !_{q}^{(0)} + p+k} + \frac{F_{0,\infty}^{(2)} (k;p;q)}{1 + !_{q+p}^{(0)} + !_{q}^{(0)} + p+k} + \frac{F_{0,\infty}^{(2)} (k;p;q)}{1 + !_{q+p}^{(0)} + !_{q}^{(0)} + p+k} + \frac{F_{0,\infty}^{(3)} (k;p;q)}{1 + !_{q+p}^{(0)} + !_{q}^{(0)} + p+k} + t_{p} [(12a)] + t_{p} [(12a)]$$

with

$$F_{0}^{(1)}(k;p;q) = n_{F} \left(\begin{smallmatrix} 0 \\ p+k \end{smallmatrix} \right) \left[n_{B} \left(! \begin{smallmatrix} 0 \\ q \end{smallmatrix} \right) n_{B} \left(! \begin{smallmatrix} 0 \\ q+p \end{smallmatrix} \right) \right] + n_{B} \left(! \begin{smallmatrix} 0 \\ q+p \end{smallmatrix} \right) \left[1 + n_{B} \left(! \begin{smallmatrix} 0 \\ q \end{smallmatrix} \right) \right]; \quad (13a)$$

$$F_{0}^{(2)}(k;p;q) = n_{F} \left({\binom{0}{p+k}} \right) [n_{B} \left({\binom{0}{q+p}} \right) n_{B} \left({\binom{1}{q}} \right) \\ + n_{B} \left({\binom{1}{q}} \right) [1 + n_{B} \left({\binom{0}{q+p}} \right)];$$
(13b)

$$F_{0}^{(3)} \otimes (k;p;q) = n_{F} \left({\binom{0}{p+k}} \right) [1 + n_{B} \left({\binom{0}{q+p}} \right) + n_{B} \left({\binom{1}{q}} \right)]$$

+ $n_{B} \left({\binom{1}{q}} \right) n_{B} \left({\binom{0}{q+p}} \right);$ (13c)

$$F_{0}^{(4)}(k;p;q) = [1 + n_{B}(!_{q}^{(0)})][1 + n_{B}(!_{q+p}^{(0)})]$$

$$n_{F}(_{p+k}^{(0)})[1 + n_{B}(!_{q+p}^{(0)})]$$

$$+ n_{B}(!_{q}^{(0)})]; \qquad (13d)$$

$$L_{p_{0}}^{(1)}(k;p;p^{0}) = n_{F} \begin{pmatrix} {\binom{0}{p+p^{0}}} \\ p+p^{0} \end{pmatrix} [1 \quad n_{F} \begin{pmatrix} {\binom{0}{p^{0}}} \end{pmatrix}] \quad n_{B} \begin{pmatrix} {\binom{0}{k+p}} \\ k+p \end{pmatrix}$$
$$[n_{F} \begin{pmatrix} {\binom{0}{p^{0}}} \end{pmatrix} \quad n_{F} \begin{pmatrix} {\binom{0}{p+p^{0}}} \\ p+p^{0} \end{pmatrix}]; \quad (13e)$$

$$L^{(2)}_{0 \ 0} (k;p;p^{0}) = n_{F} \left({\binom{0}{p+p^{0}}} \right) [1 \ n_{F} \left({\binom{0}{p^{0}}} \right)] + [1 + n_{B} \left({\binom{0}{k+p}} \right)] \\ + [1 + n_{B} \left({\binom{0}{k+p}} \right)] \\ [n_{F} \left({\binom{0}{p^{0}}} \right) \ n_{F} \left({\binom{0}{p+p^{0}}} \right)];$$
(13f)

and $n_{\rm F}$ ($_{\rm k}^{(\)}$) and $n_{\rm B}$ (! $_{\rm k}^{(\)}$) are the ferm ion and boson distribution functions, respectively. W ithin the ferm ion-spin theory, the spin uctuation couples only to spinons, while the charge uctuation couples only to holons $^{13;14}$, this is because that the local constraint with no doubly occupied has been treated properly, and therefore leads to disappearing of the extra gauge degree of freedom related with the local constraint under the charge-spin separation. How ever, the strong correlation between holons and spinons still is included self-consistently through the holon's order param eters entering the spinon's propagator and the spinon's order param eters and spinons are responsible for the optical, transport and m agnetic behaviors.

III. CHARGE TRANSPORT

Among the striking features of the unusual physical properties stands out the extraordinary charge transport^{1;2}. The frequency-and tem perature-dependent conductivity is a powerful probe for system s of interacting electrons, and provides very detailed informations of the excitations, which interacts with carriers in the norm al-state and m ight play an important role in the superconductivity. In the fram ework of the ferm ion-spin theory, the charge uctuation couples only to holons as m entioned above, and therefore as in the doped single layer case¹³, the conductivity of the doped bilayer triangular antiferrom egnet is obtained as,

$$(!) = \frac{\text{Im}^{(h)}(!)}{!}; \qquad (14)$$

where $^{(h)}(!)$ is the holon current-current correlation function, and is de ned as $^{(h)}(^{0}) =$ hT j^(h)()j^(h)()i, with and ⁰ are the imaginary times, and T is the order operator. W ithin the H am iltonian (3), the current density of holons is obtained by the time derivation of the polarization operator using H eisenberg's equation of motion as,

$$j^{(h)} = 2 _{k} et_{k} ^{A} h_{ai+}^{Y} h_{ai} + 2 _{?} et_{?} (R_{2i} R_{1i}) (h_{2i}^{Y} h_{1i} h_{1i}^{Y} h_{2i}); (15)$$

where R_{1i} (R_{2i}) is the lattice site of the plane 1 (plane 2), and e is the electronic charge, which is set as the unit hereafter. This holon current-current correlation function can be calculated in term s of the full holon G reen's function g (k;!). A fler a straightforward calculation, we obtain explicitly the conductivity of the doped bilayer triangular antiferrom agnet as,

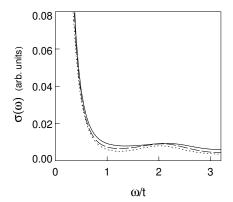


FIG.1. The conductivity at x = 0.12 (solid line), x = 0.09 (dashed line), and x = 0.06 (dotted line) in T = 0 for $t_k = J_k = 2.5$, $t_2 = t_k = 0.25$, and $J_2 = J_k = 0.25$.

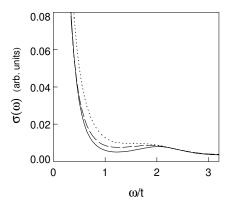


FIG.2. The conductivity in T = 0 (solid line), T = $0.3J_k$ (dashed line), T = $0.5J_k$ (dotted line) at x = 0.06 for $t_k=J_k=2.5$, $t_2=t_k=0.25$, and $J_2=J_k=0.25$.

$$(!) = {}^{(L)}(!) + {}^{(T)}(!); \qquad (16)$$

with the longitudinal and transverse parts are given by,

respectively,

where $2 = [\sin(k_x) + \sin(k_x=2)\cos(\sqrt{3}k_y=2)]^2 = 9 + [\cos(k_x=2)\sin(\sqrt{3}k_y=2)]^2 = 3$, $A_L^{(h)}(k;!) = 2 \text{Im} g_L(k;!)$ and $A_T^{(h)}(k;!) = 2 \text{Im} g_T(k;!)$ are the holon's longitudinal and transverse spectral functions.

In Fig. 1, we present the conductivity at doping x = 0.12 (solid line), x = 0.09 (dashed line), and x = 0.06 (dotted line) for parameters $t_k = J_k = 2.5$, $t_2 = t_k = 0.25$, and $J_2 = J_k = 0.25$ in temperature T = 0, where (!) shows a sharp low-energy peak and the unusual mid-infrared band separated by the charge-transfer gap of the undoped system. This low-energy peak decays fastly with increasing energy, while the charge-transfer gap is

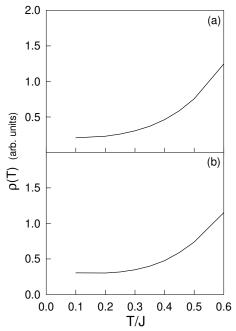


FIG.3. The resistivity at (a) x = 0:12 and (b) x = 0:06 for $t_k{=}J_k$ = 2:5, t_2 =t_k = 0:25, and J_2 =J_k = 0:25.

doping dependent, deceases with increasing dopings, and vanishes in higher doped regime. For the better understanding of the optical properties, we also study the conductivity at di erent temperatures and the results in T = 0 (solid line), T = 0.3J_k (dashed line), and T = 0.5J_k (dotted line) at x = 0.06 for $t_k=J_k = 2.5$, $t_2 = t_k = 0.25$, and $J_2 = J_k = 0.25$ are shown in Fig. 2. We therefore nd that the charge-transfer gap also decreases with increasing temperature, and disappears at higher temperatures. In the above calculations, we also nd that the conductivity (!) of the doped bilayer triangular antiferrom agnet is essentially determined by its longitudinal part ^(L.) (!), this is why in the present bilayer system the conductivity spectrum appears to re ect the single layer nature of the electronic state¹³.

Now we turn to discuss the resistivity. The resistivity is closely related to the conductivity, and can be obtained as $(T) = 1 = \lim_{n \to \infty} (!)$. We have performed the calculation for (T), and the results at x = 0.12 and x = 0.06for $t_k = J_k = 2.5$, $t_2 = t_k = 0.25$, and $J_2 = J_k = 0.25$ are plotted in the Fig. 3(a) and Fig. 3(b), respectively. These results show that the tem perature-dependent resistivity of the doped bilayer triangular antiferrom agnet is characterized by the nonlinearity metallic-like behavior in the higher tem perature range, and the deviation from the m etallic-like behavior in the lower tem perature range. In com parison with the results of the doped singlar triangular antiferrom agnet¹³, it is shown that although the bilayer interaction leads to the band splitting in the electronic structure, the qualitative behavior of the charge transport is the same as in the single layer case.

Since the t-J m odel is characterized by the competition between the kinetic energy (t) and magnetic energy (J). The magnetic energy J favors the magnetic order for spins, while the kinetic energy t favors delocalization of holes and tends to destroy the magnetic order. In the present ferm ion-spin theory, although both holons and spinons contribute to the charge transport, the scattering of holons dom inates the charge transport, where the charged holon scattering rate is obtained from the full holon G reen's function (then the holon self-energy (10) and holon spectral function) by considering the holonspinon interaction. In this case, the unusual behavior in the resistivity is closely related with this competition. In the underdoped regime, the holon kinetic energy is much sm aller than the magnetic energy in lower tem peratures, therefore the magnetic uctuation is strong enough to heavily reduce the charged holon scattering and thus is responsible for the deviation from the metallic-like behavior in the resistivity. W ith increasing tem peratures, the holon kinetic energy is increased, while the spinon magnetic energy is decreased. In the region where the holon kinetic energy is much larger than the spinon magnetic energy at high temperatures, the charged holon scattering would give rise to the metallic-like behavior in the resistivity.

IV.SPIN RESPONSE

The antiferrom agnetic spin correlation is responsible for the nuclear magnetic resonance (NMR), nuclear quadrupole resonance (NQR), and especially for the tem – perature dependence of the spin-lattice relaxation rate^{1;2}. This spin response is manifested by the dynamical spin structure factor S (k;!), which can be obtained in the present bilayer triangular antiferrom agnet as,

$$S(k;!) = 2[l + n_{B}(!)][2 \text{Im} D_{L}(k;!) + 2 \text{Im} D_{T}(k;!)]$$
$$= \frac{4[l + n_{B}(!)](B_{k}^{(1)})^{2} \text{Im} (s)_{LT}(k;!)}{A + B}; \quad (18)$$

where $A = [!^2 (!_k^{(1)})^2 B_k^{(1)} \operatorname{Re} {}_{LT}^{(s)} (k;!)]^2$, $B = B_k^{(1)} \operatorname{Im} {}_{LT}^{(s)} (k;!)]^2$, and $\operatorname{Im} {}_{LT}^{(s)} (k;!) = \operatorname{Im} {}_{L}^{(s)} (k;!) + \operatorname{Im} {}_{T}^{(s)} (k;!)$ and $\operatorname{Re} {}_{LT}^{(s)} (k;!) = \operatorname{Re} {}_{L}^{(s)} (k;!) + \operatorname{Re} {}_{T}^{(s)} (k;!)$, while $\operatorname{Im} {}_{L}^{(s)} (k;!)$ ($\operatorname{Im} {}_{T}^{(s)} (k;!)$) and $\operatorname{Re} {}_{L}^{(s)} (k;!)$ ($\operatorname{Im} {}_{T}^{(s)} (k;!)$) and $\operatorname{Re} {}_{L}^{(s)} (k;!)$ ($\operatorname{Im} {}_{T}^{(s)} (k;!)$) and $\operatorname{Re} {}_{L}^{(s)} (k;!)$ ($\operatorname{Re} {}_{T}^{(s)} (k;!)$) are the imaginary and real parts of the second order longitudinal (transverse) spinon self-energy (11), respectively.

In Fig. 4, we present the result of the dynamical spin structure factor S (k;!) in the $(k_x;k_y)$ plane at (a) x = 0.02 and (b) x = 0.06 in $T = 0.1J_k$ and $! = 0.05J_k$ for $t_k=J_k = 2.5$, $t_2=t_k = 0.2$, and $J_2=J_k = 0.2$, hereafter we use the units of [2 =3;2 =3]. Obviously, there is a commensurate-incommensurate transition in the spin uctuation with dopings. Near the half-lling, the spin

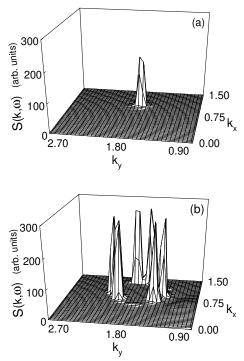


FIG.4. The dynamical spin structure factor in the $(k_x;k_y)$ plane at (a) x = 0.02 and (b) x = 0.06 in $T = 0.1J_k$ and $! = 0.05J_k$ for $t_k=J_k = 2.5$, $t_2 = t_k = 0.2$, and $J_2 = J_k = 0.2$.

uctuation is commensurate, and the position of the commensurate neutron scattering peak is boated at the antiferrom agnetic wave vector Q = [1; 3]. However, this commensurate peak is split into six peaks in the underdoped regime, while the positions of these incommensurate peaks are located at [(1 $p \ge x$); (3 y)], $\left[(1 - \frac{x}{2}); (3 - \frac{y}{2}) \right]$, and $\left[(1 - \frac{x}{2}); (3 - \frac{y}{2}) \right]$, with $\left[(\frac{2}{3} + \frac{2}{y}) = \frac{(\frac{0}{3})^2 + (\frac{0}{3})^2}{(\frac{0}{3})^2 + (\frac{0}{3})^2 + (\frac{0}{3})^2} \right]$. The

calculated dynam ical spin structure factor spectrum has been used to extract the doping dependence of the incom m ensurability parameter (x), de ned as the deviation of the peak position from the antiferrom agnetic wave vector Q, and the result is plotted in Fig. 5, where (x) increases with the hole concentration in lower dopings, but it saturates at higher dopings, and is qualitatively sim ilar to the results of the doped single layer triangular antiferrom agnet¹⁴. For the further understanding of the m agnetic properties, we have m ade a series of scans for S (k;!) at di erent tem peratures and energies, and nd that as in the single layer case, the weight of the incom m ensurate peaks are broadened and suppressed with increasing tem peratures. M oreover, although the positions of the incom m ensurate peaks are alm ost energy independent, the weight of these peaks decreases with increasing energy, and tends to vanish at high energies. This re ects that the inverse lifetime of the spin excitations increases with increasing energy.

The physical origin of the incom mensurate magnetic uctuation in the doped bilayer triangular antiferrom agnet is the almost same as in the single layer case¹⁴, and is induced by the spinon self-energy renormalization due to holons, i.e., the mechanism of the incom – mensurate type of structure away from the half-lling is most likely related to the holon motion. S (k; !) in Eq. (18) exhibits peaks when the incoming neutron energy ! is equal to the renormalized spin excitation $E_k^2 = (!_k^{(1)})^2 + B_k^{(1)} \text{Re}_{LT}^{(s)} (k; E_k)$, i.e., $[!^2 (!_{k_c}^{(1)})^2 = B_{k_c}^{(1)} \text{Re}_{LT}^{(s)} (k; E_c)^2 = 0$ for certain critical wave vectors k_c . The height of these peaks then

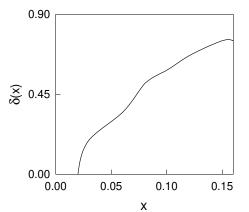


FIG.5. The doping dependence of the incom m ensurability (x) of the antiferrom agnetic uctuations.

is determined by the imaginary part of the spinon selfenergy 1=Im ${}^{(s)}_{\rm L\,T}$ (k_;!). This renorm alized spin excitation is doping and tem perature dependent. Near halflling, the spin excitations are centered around the antiferrom agnetic wave vector Q, so the commensurate antiferrom agnetic peak appears there. Upon doping, the holes disturb the antiferrom agnetic background. W ithin the ferm ion-spin fram ework, as a result of self-consistent motion of holons and spinons, the incommensurate antiferrom agnetism is developed beyond certain critical doping, which means that the low-energy spin excitations drift away from the antiferrom agnetic wave vector, where the physics is dom inated by the spinon self-energy Re $_{\rm L}^{\rm (s)}$ (k;!) renorm alization due to holons. This is why the mobile holes are the key factor leading to the incom m ensurate antiferrom agnetism, while the spinon energy dependence is ascribed purely to self-energy e ects which arise from the holon-spinon interaction. Since the height of the incom m ensurate peaks is determ ined by dam ping, it is fully understandable that they are suppressed as the neutron energy ! and tem perature are increased.

V.SUMMARY AND DISCUSSIONS

In the above discussions, the central concern of the charge transport and spin response in the doped bilayer triangular antiferrom agnet is the quasi-two dimensionality of the electron state, then the charge transport is mainly determined by the longitudinal charged holon uctuation, and spin response is dominated by the longitudinal spinon uctuation. On the other hand, our present study also indicates that the physical properties of the doped antiferrom agnet are heavily dependent on the electron geom etry structure. Unlike the doped square antiferrom agnet, the resistivity in the doped triangular antiferrom agnet does not exhibits a linear m etallic-like behavior in the higher temperature range as would be expected for the doped square antiferrom agnet, while six incommensurate neutron scattering peaks in the doped triangular antiferrom agnet are incom patible with these in the doped square antiferrom agnet, where four incom m ensurate peaks are observed 5^{5} .

In sum m ary, we have discussed the charge transport and spin response of the doped bilayer triangular antiferrom agnet within the fram ework of the ferm ion-spin theory based on the t-J m odel. It is shown that although the bilayer interaction leads to the band splitting in the electronic structure, the qualitative behaviors of the charge transport and spin response are the same as in the single layer case^{13;14}. The conductivity spectrum shows the low -energy peak and unusualm idinfrared band separated by the charge-transfer gap, while the tem perature dependent resistivity is characterized by the nonlinearity m etallic-like behavior in the higher tem perature range, and the deviation from the m etallic-like behavior in the low energy perature range. The commensurate neutron scattering peak near the half-lling is split into six incommensurate peaks in the underdoped regime, with the incommensurability increases with the hole concentration at lower dopings, and saturates at higher dopings.

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